

TECHNICAL DATA
DATA SHEET 455, REV. A

HERMETIC POWER SCHOTTKY RECTIFIER
Ultra Low Reverse Leakage
200°C Operating Temperature

(S-100 for JANTXV equivalent screening; SS for JANS equivalent screening available)

Applications:

- Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

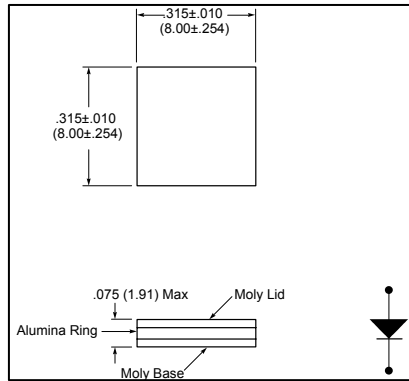
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T _C =100 °C)	I _o	30	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	570	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V) (per leg)	C _T	1000	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	R _{θJC}	0.50	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	Top	-65 to + 200	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Tstg	-65 to + 175	°C

ELECTRICAL CHARACTERISTICS

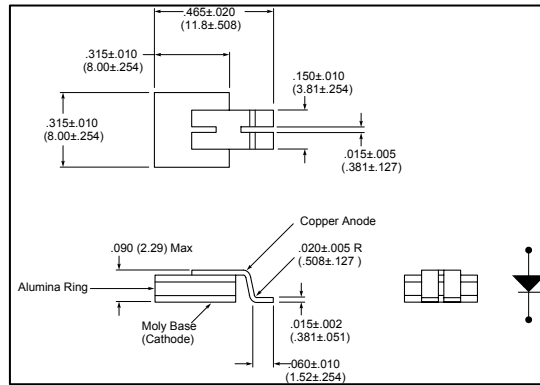
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 30 Amps) T _J = 25 °C T _J = 125 °C	V _f	0.84 0.68	Volts
MAXIMUM REVERSE CURRENT (I _r @ 100V PIV) T _J = 25 °C T _J = 125 °C	I _r	0.20 2.0	mA

MECHANICAL DIMENSIONS: In Inches / mm

SHD-2



SHD-2B



PINOUT TABLE

TYPE	PIN 1 (Base)	PIN 2
SINGLE RECTIFIER	CATHODE	ANODE

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